Thick Film Hybrid IC

STK4046XI



AF Power Amplifier (Split Power Supply) (120 W min, THD = 0.008%)

Features

- Compact packaging supports slimmer set designs
- Series designed from 50 up to 150 W and pincompatibility
- Simpler heat sink design facilitates thermal design of slim stereo sets
- Current mirror circuit, cascade circuit and purecomplimentary circuit application reduce distortion to 0.008 %
- Supports addition of electronic circuits for thermal shutdown and load-short protection circuit as well as pop noise muting which occurs when the power supply switch is turned on and off.

Package Dimensions

unit: mm

4051A



Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Condition	Rating	Unit
Maximum supply voltage	V _{CC} max		± 80	V
Thermal resistance	өј-с		1.4	°C/W
Junction temperature	Tj		150	°C
Operating substrate temperature	Tc		125	°C
Storage temperature	Tstg		-30 to +125	°C

Recommended Operational Conditions at Ta = $25^{\circ}C$

Parameter	Symbol	Condition	Rating	Unit
Recommended supply voltage	V _{CC}		± 55	V
Load resistance	RL		8	Ω

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Operating Characteristics

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at Ta = 25°C, V_{CC} = ± 55 V, R_L = 8 \Omega, VG = 40 dB, Rg = 600 \Omega, 100 k LPF ON, R_L (non-inductive)
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Parameter		Condition	Rating			
	Symbol		min	typ	max	Unit
Quiescent current	I _{CCO}	$V_{CC} = \pm 66 V$	15		120	mA
Output power	Po	THD = 0.008 %, f = 20 Hz to 20 kHz	120			W
Total harmonic distortion	THD	P _O = 1.0 W, f = 1 kHz			0.008	%
Frequency response	fL, fH	$P_0 = 1.0 \text{ W}, \frac{+0}{-3} \text{ dB}$		20 to 50k		Hz
Input resistance	r _i	P _O = 1.0 W, f = 1 kHz		55		kΩ
Output noise voltage	V _{NO} *	$V_{CC} = \pm 66 \text{ V}, \text{Rg} = 10 \text{ k}\Omega$			1.2	mVrms
Neutral voltage	V _N	V _{CC} = ± 66 V	-70	0	+ 70	mV

Note: Use rated power supply for test unless otherwise specified.

* Output noise voltage represents the peak value on the rms scale (VTVM). The noise voltage waveform does not include the pulse noise.





Equivalent Circuit





Application Circuit: 120W min Single Channel AF Power Amplifier

Sample Printed Circuit Pattern for Application Circuit (Copper-foiled side)



Unit (resistance: Ω, capacitance: F)

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